2SC4964

Silicon NPN Epitaxial

HITACHI

ADE-208-005 1st. Edition

Application

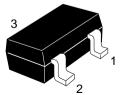
VHF / UHF RF switch

Features

- Low Ron and high performance for RF switch.
- Capable of high density mounting.

Outline

MPAK



- 1. Emitter
- 2. Base
- 3. Collector



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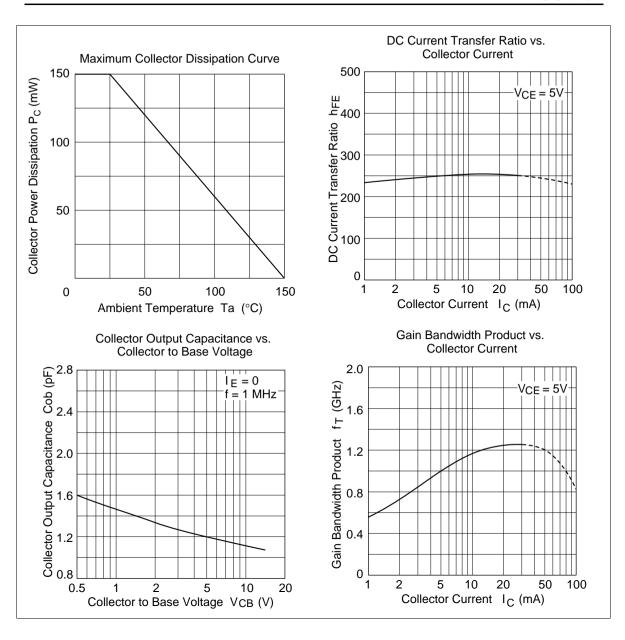
Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	12	V
Collector to emitter voltage	V _{CEO}	8	V
Emitter to base voltage	V_{EBO}	3	V
Collector current	I _c	100	mA
Collector power dissipation	P _c	150	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

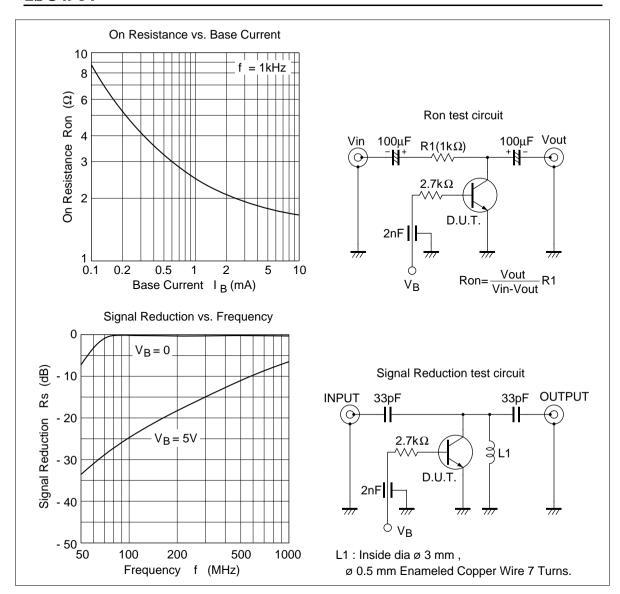
Electrical Characteristics ($Ta = 25^{\circ}C$)

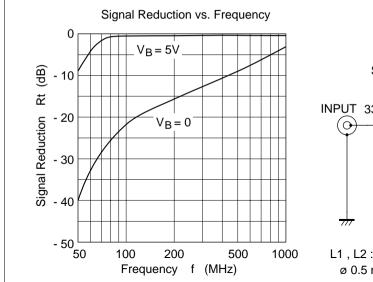
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	12	_	_	V	$I_{C} = 10 \ \mu A, \ I_{E} = 0$
Collector cutoff current	I _{CBO}	_	_	1	μΑ	V _{CB} = 10 V, I _E = 0
	I _{CEO}	_	_	1	mA	$V_{CE} = 8 \text{ V}, R_{BE} = \infty$
Emitter cutoff current	I_{EBO}	_	_	10	μΑ	$V_{EB} = 3 \text{ V}, I_{C} = 0$
DC current transfer ratio	h_{FE}	100	250	600		$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	200	300	mV	$I_C = 80 \text{ mA}, I_B = 5 \text{ mA}$
Collector output capacitance	Cob	_	1.2	1.6	pF	$V_{CB} = 5 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$
On resistance	Ron	_	2.0	_	Ω	I _B = 2.5 mA, f = 1 kHz

Note: Marking is "YV-".

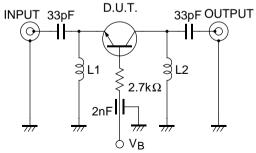


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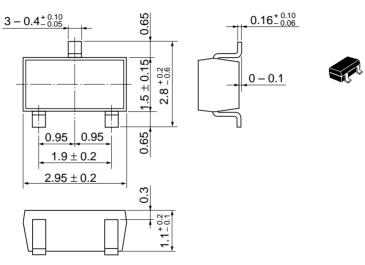


Signal Reduction test circuit



L1 , L2 : Inside dia ø 3 mm , ø 0.5 mm Enameled Copper Wire 7 Turns.

Unit: mm



Hitachi Code	MPAK
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.011 g

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Hitachi, Ltd.

Semiconductor & Integrated Circuits.

Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL NorthAmerica : http:semiconductor.hitachi.com/

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For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Hitachi Europe GmbH Electronic components Group Dornacher Stra§e 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0

Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.

Electronic Components Group.

Whitebrook Park Lower Cookham Road Maidenhead

Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000

Tel: <44> (1628) 585000 Fax: <44> (1628) 778322 Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd.
Taipei Branch Office
3F, Hung Kuo Building. No.167,
Tun-Hwa North Road, Taipei (105)
Tel: <886> (2) 2718-3666

Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower, World Finance Centre,
Harbour City, Canton Road, Tsim Sha Tsui,
Kowloon, Hong Kong
Tel: <852> (2) 735 9218

Fax: <852> (2) 735 9218 Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

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